

# PHOTO DIODE

## **NDL5551P Series**

## 1 000 to 1 600 nm OPTICAL FIBER COMMUNICATIONS $\phi$ 50 $\mu$ m InGaAs AVALANCHE PHOTO DIODE MODULE

#### **DESCRIPTION**

NDL5551P Series is InGaAs avalanche photo diode modules with multimode fiber. They are designed for detectors of long wavelength transmission systems and cover the wavelength range between 1 000 and 1 600 nm.

#### **FEATURES**

Smaller dark current ID = 5 nA

• High quantum efficiency  $\eta = 90 \% @ \lambda = 1 300 \text{ nm}, M = 1$ 

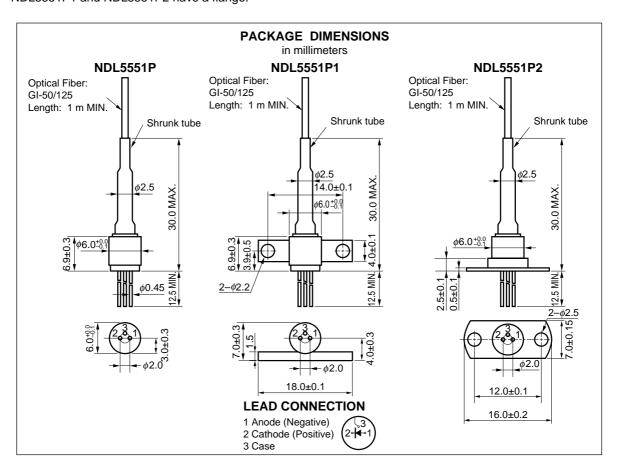
 $\eta = 77 \% @ \lambda = 1550 \text{ nm}, M = 1$ 

High Speed response
 fc = 1.2 GHz @M = 20

• Detecting area size  $\phi 50 \mu m$ 

Coaxial module with multimode fiber (GI-50/125)

NDL5551P1 and NDL5551P2 have a flange.



The information in this document is subject to change without notice.

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### **★** ORDERING INFORMATION

Part Number	Available Connector				
NDL5551P	Without Connector	no flange			
NDL5551PC	With FC-PC Connector				
NDL5551PD	With SC-PC Connector				
NDL5551P1	Without Connector	flat mount flange			
NDL5551P1C	With FC-PC Connector				
NDL5551P1D	With SC-PC Connector				
NDL5551P2	Without Connector	vertical flange			
NDL5551P2C	With FC-PC Connector				
NDL5551P2D	With SC-PC Connector				

## ABSOLUTE MAXIMUM RATINGS (Tc = 25 °C)

Parameter	Symbol	Ratings	Unit
Forward Current	lf	10	mA
Reverse Current	lR	0.5	mA
Operating Case Temperature	Tc	-40 to +85	°C
Storage Temperature	Tstg	-40 to +85	°C

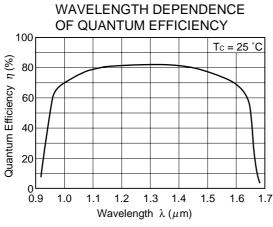
## ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25 °C)

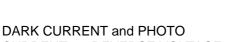
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	Io = 100 μA	50	70	100	V
Temperature Coefficient of Reverse Breakdown Voltage	δ*1			0.2		%/°C
Dark Current	ΙD	$V_R = V_{(BR)R} \times 0.9$		5	30	nA
Multiplied Dark Current	Ірм	M = 2 to 10		1	5	nA
Terminal Capacitance	Ct	$V_R = V_{(BR)R} \times 0.9$ , $f = 1 \text{ MHz}$		0.4	0.75	pF
Cut-off Frequency	fc	M = 10	1	1.5		GHz
		M = 20		1.2		
Quantum Efficiency	η	λ = 1 300 nm, M = 1	76	90		%
		λ = 1 550 nm, M = 1	65	77		
Responsivity	S	λ = 1 300 nm, M = 1	0.8	0.94		A/W
		λ = 1 550 nm, M = 1	0.81	0.96		
Multiplication Factor	М	$\lambda$ = 1 300 nm, IP0 = 1.0 $\mu$ A	30	40		
		$V_R = V (@ I_D = 1 \mu A)$				
Excess Noise Exponent	х	$\lambda$ = 1 300 nm, 1550 nm, I <sub>P0</sub> = 1.0 $\mu$ A		0.7		
Excess Noise Factor	F	M = 10, f = 35 MHz, B = 1 MHz		5		

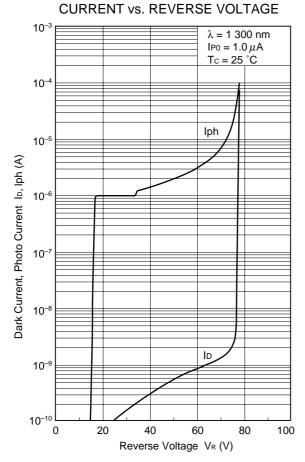
\*1: 
$$\delta = \frac{V_{(BR)R} < 25 \, ^{\circ}C + \Delta T \, ^{\circ}C > -V_{(BR)R} < 25 \, ^{\circ}C >}{\Delta T \, ^{\circ}C \, \cdot \, V_{(BR)R} < 25 \, ^{\circ}C >}$$

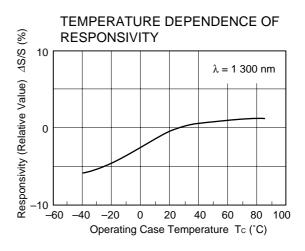
#### TYPICAL CHARACTERISTICS

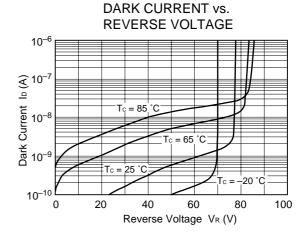


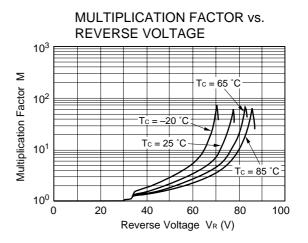


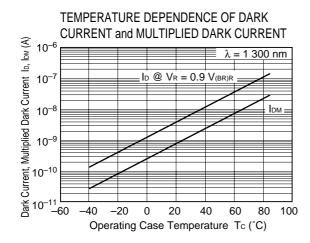


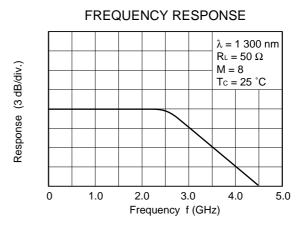


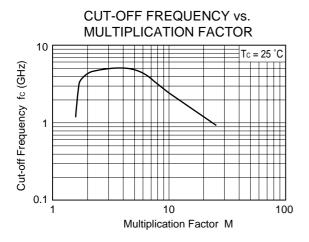


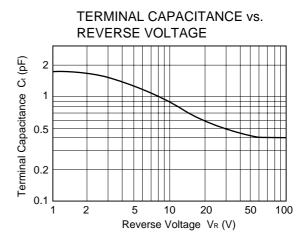


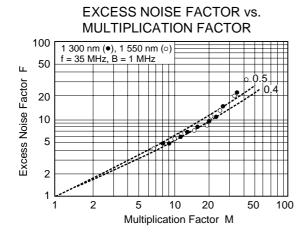










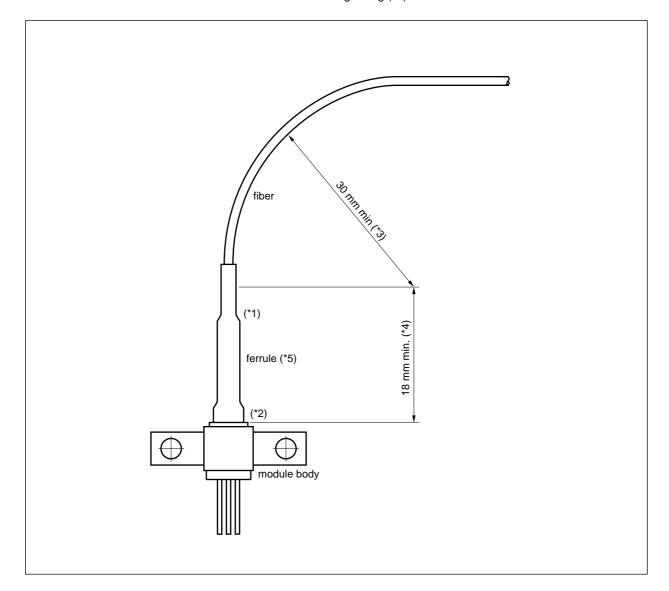


#### HANDLING PRECAUTION for PD/APD MODULE

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The NEC PD/APD module has heat shrink tubing to protect the ferrule edge (\*1) and the junction between the ferrule and the module body (\*2). In order to avoid breaking the fiber and/or optical coupling degradation, NEC recommends the following handling precautions.

- 1. Do not make the fiber bend radius less than 30 mm (\*3).
- 2. Do not bend the fiber within the 18 mm section from the module body (\*4).
- 3. Do not stress the ferrule with a lateral force exceeding 500 g (\*5).



### **★** InGaAs APD/PD FAMILY

Features	APD		PIN-PD				
Packages	φ30 μm (for 2.5 Gb/s)	φ50 μm (for 2.5 Gb/s)	<i>φ</i> 50 μm	<i>φ</i> 80 μm	φ50 μm (for 2.5 Gb/s)	<i>φ</i> 80 μm	Remarks
TO-18 type Can	NDL5530		NDL5500	NDL5510			3 pins
TO-18 type Can with Micro Lens					NDL5490L*3,4	NDL5405L	3 pins
Small Can φ5.6 μm	NDL5531				NDL5490*3,4		
Chip on Carrier	NDL5530C	NDL5520C	NDL5500C	NDL5510C			
Receptacle Module						NDL5471RC NDL5471RD	3 pins RC: FC receptacle RD: SC receptacle
Coaxial Module with MMF		NDL5521P NDL5521P1 NDL5521P2	NDL5551P NDL5551P1 NDL5551P2 NDL5553P <sup>*1</sup> NDL5553P1 <sup>*1</sup> NDL5553P2 <sup>*1</sup>	NDL5561P <sup>12</sup> NDL5561P1 <sup>12</sup> NDL5561P2 <sup>12</sup>		NDL5461P NDL5461P1 NDL5461P2	P1, P2: With flange
Coaxial Module with SMF			NDL5553PS*1 NDL5553P1S*1 NDL5553P2S*1			NDL5481P <sup>*5</sup> NDL5481P1 <sup>*5</sup> NDL5481P2 <sup>*5</sup>	
14-pin DIP Module with TEC			NDL5506P NDL5506PS				ΔT = 45 K (@ Ic = 1.1 A) PS: With SMF
6-pin BFY Module with MMF		NDL5522P			NDL5422P		With Pre-AMP

- \*1 For OTDR
- \*2 With GI-62.5/125
- \*3 Under development
- \*4 Internal pre-amplifier for 1Gb/s
- \*5 For analog application (optical CATV)

**Remark** Modules are available with FC-PC connector or optional SC-PC connector.

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## **REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system	IEI-1205
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Semiconductor device package manual	IEI-1213
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

#### CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstance break the hermetic seal.

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- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
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Anti-radioactive design is not implemented in this product.

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